

Manufactured using a new die package, the new A750Pi and A650Si/Sc Series embedded solid state drives (SSDs) are breaking endurance records. Compared with other 3D TLC drives, they deliver 66% higher endurance in native triple level cell (TLC) mode and 50% higher in pseudo single level cell (pSLC) mode, making them on par with drives built on multi-level cell (MLC) and SLC flash, respectively.

Key Features

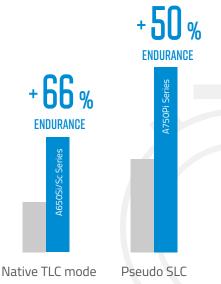
- Available in M.2 2280/2242, 2.5" & mSATA form factors
- Endurance on par with MLC & SLC flash
- 120 to 1920 GB capacities for native TLC (A650Si/A650Sc)
- 80 to 640 GB capacities for pSLC (A750Pi)
- Industrial temperature operable (A750Pi/A650Si)
- MCU-based Power Loss Protection design with Level 4 data-in-flight) protection
- LDPC ECC & RAID support
- End-to-end data path protection
- SED features*

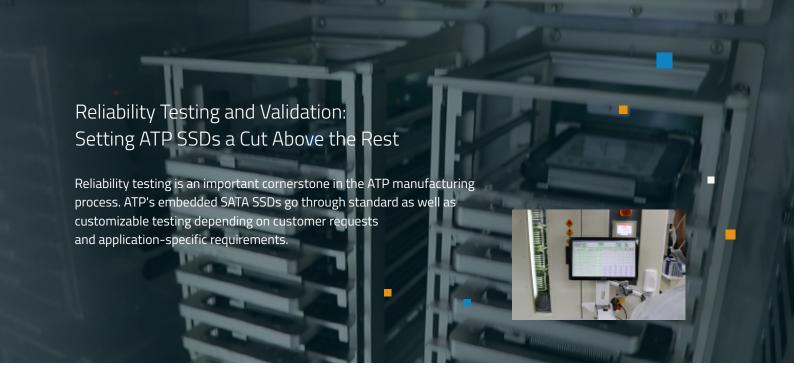
*Optional

Why A750Pi and A650Si/Sc Series ATP SSDs?

Endurance Suited for Write-Intensive Workloads

ATP's new 3D TLC SSDs leap to new endurance heights, thanks to a new die package. In native TLC mode, the A650Si/Sc Series delivers 66% higher TBW than other SSDs to achieve near-MLC endurance. For the A750Pi Series in pSLC mode, it's 50% higher to match SLC endurance.







Four-Corner, Temperature Cycling, and Power Cycling Tests

Demonstrate reliable performance and stored data handling without data miscompare even under harsh conditions.



End-of-Life Validation Test

Makes sure that ATP SSDs perform reliably and maintain data integrity over their life span (and even beyond) as required.



PCBA Solderability Validation

Ensures effective bonding of components on the printed circuit board assembly (PCBA) for reliable electro-mechanical connections.



Reliability Demonstration Test (RDT)

Validates the mean time between failures (MTBF) rating of the drive through actual drive-level testing instead of relying on reliability prediction systems.

MCU-Based Power Loss Protection Design

The newly designed power loss protection (PLP) array includes a power management IC (PMIC) and firmware-programmable MCU (microcontroller unit), allowing the PLP array to perform intelligently in various temperatures, power glitches and charge states.



MCU



PLP array

Product Specifications

		2.5"			M.2 2280		
Product Line	A750Pi	A650Si	A650Sc	A750Pi	A650Si	A650Sc	
Flash Type			3D ⁻	TLC			
Flash Mode	Pseudo SLC	TLC	TLC	Pseudo SLC	TLC	TLC	
Operating Temperature (Tcase) ¹	-40°C	to 85°C	0°C to 70°C	-40°C	to 85°C	0°C to 70°C	
Power Loss Protection Options	Hardware + Firmware Based						
Optional SED Features	-	AES 256-bit Encry	ption, TCG Opal 2.0	-	AES 256-bit Encry	ption, TCG Opal 2.0	
Capacity	80 GB to 640 GB	120 GB to 1920 GB	120 GB to 1920 GB	80 GB to 320 GB	120 GB to 960 GB	120 GB to 960 GB	
	Performance						
Performance Sequential Read (MB/s) up to	560	560	560	560	560	560	
Performance Sequential Write (MB/s) up to	520	500	500	520	440	440	
Performance Random Read IOPS (4K,QD32) up to	95,000	100,000	100,000	94,000	100,000	100,000	
Performance Random Writes IOPS (4K, QD32) up to	86,000	91,000	91,000	86,000	88,000	88,000	
	Endurance and Reliability						
Endurance (TBW)² up to	38,400 TB	9,310 TB	9,310 TB	19,200 TB	4,655 TB	4,655 TB	
ReliabilityMTBF @ 25°C	>2,000,000 hours						
Data Retention @ 30°C³	5 years (with 10% P/E cycle)						
	Others						
Power Consumption	5V Input Power	5V Input Power	5V Input Power	3.3V Input Power	3.3V Input Power	3.3V Input Power	
Dimensions: L x W x H (mm)	100 x 69.9 x 7/9.2	100 x 69.9 x 7/9.2	100 x 69.9 x 7/9.2	80 x 22 x 3.35	80 x 22 x 3.35	80 x 22 x 3.35	
Certifications	CE, FCC, BSMI, UKCA, RoHS, REACH						
Warranty	5 years	2 years	2 years	5 years	2 years	2 years	
		M.2 2242			mSATA		
Product Line	A750Pi	M.2 2242 A650Si	A650Sc	A750Pi	mSATA A650Si	A650Sc	
Product Line Flash Type	A750Pi		A650Sc 3D T			A650Sc	
	A750Pi Pseudo SLC					A650Sc TLC	
Flash Type	Pseudo SLC	A650Si	3D 1	FLC Pseudo SLC	A650Si		
Flash Type Flash Mode Operating Temperature	Pseudo SLC	A650Si TLC	3D T	Pseudo SLC -40°C	A650Si TLC	TLC	
Flash Type Flash Mode Operating Temperature (Tcase)¹ Power Loss Protection	Pseudo SLC	A650Si TLC to 85°C	3D 7 TLC 0°C to 70°C	Pseudo SLC -40°C	A650Si TLC to 85°C	TLC	
Flash Type Flash Mode Operating Temperature (Tcase)¹ Power Loss Protection Options	Pseudo SLC	A650Si TLC to 85°C	3D T TLC 0°C to 70°C Hardware + Fir	Pseudo SLC -40°C	A650Si TLC to 85°C	TLC 0°C to 70°C option, TCG Opal 2.0	
Flash Type Flash Mode Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features	Pseudo SLC -40°C t	A650Si TLC to 85°C AES 256-bit Encry	3D 7 TLC 0°C to 70°C Hardware + Fir	Pseudo SLC -40°C mware Based - 80 GB to 160 GB	A650Si TLC to 85°C AES 256-bit Encry	TLC 0°C to 70°C	
Flash Type Flash Mode Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity Performance Sequential	Pseudo SLC -40°C t	A650Si TLC to 85°C AES 256-bit Encry	3D 7 TLC 0°C to 70°C Hardware + Fir rption, TCG Opal 2.0 120 GB to 480 GB	Pseudo SLC -40°C mware Based - 80 GB to 160 GB	A650Si TLC to 85°C AES 256-bit Encry	TLC 0°C to 70°C ption, TCG Opal 2.0	
Flash Type Flash Mode Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity	Pseudo SLC -40°C f - 80 GB to 160 GB	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB	TLC O°C to 70°C Hardware + Fir ption, TCG Opal 2.0 120 GB to 480 GB Perforr	Pseudo SLC -40°C mware Based - 80 GB to 160 GB	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB	TLC 0°C to 70°C option, TCG Opal 2.0 120 GB to 480 GB	
Flash Type Flash Mode Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity Performance Sequential Read (MB/s) up to Performance Sequential	Pseudo SLC -40°C f	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB	TLC 0°C to 70°C Hardware + Fire the second of the second	Pseudo SLC -40°C mware Based - 80 GB to 160 GB mance 560	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB	TLC 0°C to 70°C eption, TCG Opal 2.0 120 GB to 480 GB 560	
Flash Type Flash Mode Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity Performance Sequential Read (MB/s) up to Performance Sequential Write (MB/s) up to Performance Random Read	Pseudo SLC -40°C 1 - 80 GB to 160 GB 560 520	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB 560 440	TLC 0°C to 70°C Hardware + Fire prion, TCG Opal 2.0 120 GB to 480 GB Perform 560 440	Pseudo SLC -40°C mware Based - 80 GB to 160 GB mance 560 520	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB 560 440	TLC 0°C to 70°C ption, TCG Opal 2.0 120 GB to 480 GB 560 440	
Flash Type Flash Mode Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity Performance Sequential Read (MB/s) up to Performance Sequential Write (MB/s) up to Performance Random Read IOPS (4K,QD32) up to Performance Random Writes	Pseudo SLC -40°C 1 - 80 GB to 160 GB 560 520 84,500	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB 560 440 100,000	3D 7 TLC 0°C to 70°C Hardware + Fir ption, TCG Opal 2.0 120 GB to 480 GB Perforr 560 440 100,000	Pseudo SLC -40°C mware Based - 80 GB to 160 GB mance 560 520 94,000 85,000	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB 560 440 100,000	TLC 0°C to 70°C Pption, TCG Opal 2.0 120 GB to 480 GB 560 440 100,000	
Flash Type Flash Mode Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity Performance Sequential Read (MB/s) up to Performance Sequential Write (MB/s) up to Performance Random Read IOPS (4K,QD32) up to Performance Random Writes	Pseudo SLC -40°C 1 - 80 GB to 160 GB 560 520 84,500	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB 560 440 100,000	3D 7 TLC 0°C to 70°C Hardware + Fir rption, TCG Opal 2.0 120 GB to 480 GB Perforr 560 440 100,000 88,000	Pseudo SLC -40°C mware Based - 80 GB to 160 GB mance 560 520 94,000 85,000	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB 560 440 100,000	TLC 0°C to 70°C Pption, TCG Opal 2.0 120 GB to 480 GB 560 440 100,000	
Flash Type Flash Mode Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity Performance Sequential Read (MB/s) up to Performance Sequential Write (MB/s) up to Performance Random Read IOPS (4K,QD32) up to Performance Random Writes IOPS (4K,QD32) up to	Pseudo SLC -40°C 1 - 80 GB to 160 GB 560 520 84,500 84,500	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB 560 440 100,000 88,000	3D 7 TLC 0°C to 70°C Hardware + Fir rption, TCG Opal 2.0 120 GB to 480 GB Perforr 560 440 100,000 88,000 Endurance ar	Pseudo SLC -40°C mware Based - 80 GB to 160 GB mance 560 520 94,000 85,000 and Reliability 9,600 TB	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB 560 440 100,000 88,000	TLC 0°C to 70°C Pption, TCG Opal 2.0 120 GB to 480 GB 560 440 100,000 88,000	
Flash Type Flash Mode Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity Performance Sequential Read (MB/s) up to Performance Sequential Write (MB/s) up to Performance Random Read IOPS (4K,QD32) up to Performance Random Writes IOPS (4K, QD32) up to	Pseudo SLC -40°C 1 - 80 GB to 160 GB 560 520 84,500 84,500	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB 560 440 100,000 88,000	3D 7 TLC 0°C to 70°C Hardware + Fir rption, TCG Opal 2.0 120 GB to 480 GB Perforr 560 440 100,000 88,000 Endurance ar 2,327 TB	Pseudo SLC -40°C mware Based - 80 GB to 160 GB mance 560 520 94,000 85,000 and Reliability 9,600 TB 00 hours	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB 560 440 100,000 88,000	TLC 0°C to 70°C Pption, TCG Opal 2.0 120 GB to 480 GB 560 440 100,000 88,000	
Flash Type Flash Mode Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity Performance Sequential Read (MB/s) up to Performance Sequential Write (MB/s) up to Performance Random Read IOPS (4K,QD32) up to Performance Random Writes IOPS (4K,QD32) up to Endurance (TBW)² up to ReliabilityMTBF @ 25°C	Pseudo SLC -40°C 1 - 80 GB to 160 GB 560 520 84,500 84,500	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB 560 440 100,000 88,000	3D 7 TLC 0°C to 70°C Hardware + Fir ption, TCG Opal 2.0 120 GB to 480 GB Perforr 560 440 100,000 88,000 Endurance ar 2,327 TB >2,000,00	Pseudo SLC -40°C mware Based - 80 GB to 160 GB mance 560 520 94,000 85,000 ad Reliability 9,600 TB 00 hours 10% P/E cycle)	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB 560 440 100,000 88,000	TLC 0°C to 70°C Pption, TCG Opal 2.0 120 GB to 480 GB 560 440 100,000 88,000	
Flash Type Flash Mode Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity Performance Sequential Read (MB/s) up to Performance Sequential Write (MB/s) up to Performance Random Read IOPS (4K,QD32) up to Performance Random Writes IOPS (4K,QD32) up to Endurance (TBW)² up to ReliabilityMTBF @ 25°C	Pseudo SLC -40°C 1 - 80 GB to 160 GB 560 520 84,500 84,500	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB 560 440 100,000 88,000	3D 7 TLC 0°C to 70°C Hardware + Fir rption, TCG Opal 2.0 120 GB to 480 GB Perforr 560 440 100,000 88,000 Endurance ar 2,327 TB >2,000,00 5 years (with 1	Pseudo SLC -40°C mware Based - 80 GB to 160 GB mance 560 520 94,000 85,000 ad Reliability 9,600 TB 00 hours 10% P/E cycle)	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB 560 440 100,000 88,000	TLC 0°C to 70°C Pption, TCG Opal 2.0 120 GB to 480 GB 560 440 100,000 88,000	
Flash Type Flash Mode Operating Temperature (Tcase)¹ Power Loss Protection Options Optional SED Features Capacity Performance Sequential Read (MB/s) up to Performance Sequential Write (MB/s) up to Performance Random Read IOPS (4K,QD32) up to Performance Random Writes IOPS (4K,QD32) up to Endurance (TBW)² up to ReliabilityMTBF @ 25°C Data Retention @ 30°C³	Pseudo SLC -40°C f - 80 GB to 160 GB 560 520 84,500 84,500 9,600 TB	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB 560 440 100,000 88,000 2,327 TB	3D 7 TLC 0°C to 70°C Hardware + Fir rption, TCG Opal 2.0 120 GB to 480 GB Perforr 560 440 100,000 88,000 Endurance ar 2,327 TB >2,000,00 5 years (with 1	Pseudo SLC -40°C mware Based - 80 GB to 160 GB mance 560 520 94,000 85,000 and Reliability 9,600 TB 200 hours 10% P/E cycle) ers	A650Si TLC to 85°C AES 256-bit Encry 120 GB to 480 GB 560 440 100,000 88,000 2,327 TB	TLC 0°C to 70°C ption, TCG Opal 2.0 120 GB to 480 GE 560 440 100,000 88,000 2,327 TB	

¹ Case Temperature, the composite temperature as indicated by SMART temperature attributes.

5 years

Certifications
Warranty

2 years

CE, FCC, BSMI, UKCA, RoHS, REACH

2 years

5 years

2 years

2 years

 $^{^{\}rm 2}$ Under highest Sequential write value. May vary by density, configuration and applications.

³ Data retention value may vary across different temperature ranges. It is based on experimental results and should be used only for reference.

Order Information

Product Line	Form Factor	Capacity ¹		D/N/O control lib	
			Endurance ²	P/N Operable with Industrial Temp.	P/N Operable with Commercial Temp.
	2.5"	120 GB	582 TB	AF120GSTCJ-7BCIP	AF120GSTCJ-7BCXP
		240 GB	1,164 TB	AF240GSTCJ-7BCIP	AF240GSTCJ-7BCXP
		480 GB	2,327 TB	AF480GSTCJ-7BCIP	AF480GSTCJ-7BCXP
		960 GB	4,655 TB	AF960GSTCJ-7BCIP	AF960GSTCJ-7BCXP
		1920 GB	9,310 TB	AF1T92STCJ-7BCIP	AF1T92STCJ-7BCXP
	M.2 2242	120 GB	582 TB	AF120GSTIA-7BCIP	AF120GSTIA-7BCXP
A650Si/A650Sc (Native TLC)		240 GB	1,164 TB	AF240GSTIA-7BCIP	AF240GSTIA-7BCXP
		480 GB	2,327 TB	AF480GSTIA-7BCIP	AF480GSTIA-7BCXP
	M.2 2280	120 GB	582 TB	AF120GSTIC-7BCIP	AF120GSTIC-7BCXP
		240 GB	1,164 TB	AF240GSTIC-7BCIP	AF240GSTIC-7BCXP
		480 GB	2,327 TB	AF480GSTIC-7BCIP	AF480GSTIC-7BCXP
		960 GB	4,655 TB	AF960GSTIC-7BCIP	AF960GSTIC-7BCXP
	mSATA	120 GB	582 TB	AF120GSTHI-7BCIP	AF120GSTHI-7BCXP
		240 GB	1,164 TB	AF240GSTHI-7BCIP	AF240GSTHI-7BCXP
		480 GB	2,327 TB	AF480GSTHI-7BCIP	AF480GSTHI-7BCXP
	2.5"	80 GB	4,800 TB	AF80GSACJ-7BBIP	
		160 GB	9,600 TB	AF160GSACJ-7BBIP	
A750Pi (Pseudo SLC)		320 GB	19,200 TB	AF320GSACJ-7BBIP	
		640 GB	38,400 TB	AF640GSACJ-7BBIP	
	M.2 2242	80 GB	4,800 TB	AF80GSAIA-7BBIP	
		160 GB	9,600 TB	AF160GSAIA-7BBIP	
	M.2 2280	80 GB	4,800 TB	AF80GSAIC-7BBIP	
		160 GB	9,600 TB	AF160GSAIC-7BBIP	
		320 GB	19,200 TB	AF320GSAIC-7BBIP	
	mSATA	80 GB	4,800 TB	AF80GSAHI-7BBIP	
		160 GB	9,600 TB	AF160GSAHI-7BBIP	

¹ Amount of actual usable storage that can be utilized

Product spec and its related information are subject to change without advance notice. Please refer to www.atpinc.com for latest information

v1.0 202109

© Copyright 2021 ATP Electronics, Inc. All rights reserved.



² TBW in Sequential Write